

TOSHIBA Photocoupler GaAs IRed & Photo-Triac

TLP3503

Triac Driver **Programmable Controllers** AC-Output Module Solid State Relay

The TOSHIBA TLP3503 consists of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a 8 lead plastic DIP package.

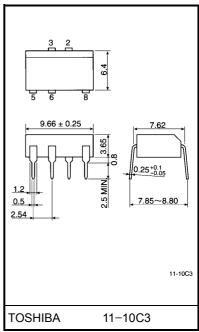
- Peak off-state voltage: 400V (min.)
- Trigger LED current: 10mA (max.)
- On-state current: 0.5A_{rms} (max.)
- Isolation voltage: 2500V_{rms} (min.)
- UL recognized: UL1577, file No. E67349
- Trigger LED Current

Classi– fication*	Trigger LED Current (mA)		Marking Of	
	V _T = 6V, Ta = 25°C		Classification	
	Min.	Max.	Olassincation	
(IFT5)	ı	5.0	T5	
(IFT7)	1	7.0	T5, T7	
Standard	_	10	T5, T7, blank	

*Ex. (IFT5); TLP3503 (IFT5)

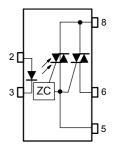
(Note)Application type name for certification test, please use standard product type name, i.e. TLP3503 (IFT5): TLP3503

Unit in mm



Weight: 0.52 g

Pin Configuration (top view)



- 2: Anode
- 3 : Cathode
- 5 : Triac gate
- 6: Triac T1

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Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
	Forward current	Ι _Ε	50	mA		
LED	Forward current derating (Ta ≥	ΔI _F / °C	-0.7	mA / °C		
	Peak forward current (100µs pu	I _{FP}	1	Α		
	Reverse voltage	V _R	5	V		
	Junction temperature	Tj	125	°C		
	Off-state output terminal voltage	V_{DRM}	400	V		
	On-state RMS current	Ta = 40°C	IT (DMO)	0.5	Α	
Detector		Ta = 60°C	I _{T (RMS)}	0.35		
	On–state current derating (Ta ≥	ΔI _T / °C	-7.2	mA / °C		
	Peak current from snubber circupulse, 120pps)	I _{SP}	2	А		
	Peak nonrepetitive surge currer	I _{TSM}	5	Α		
	Junction temperature	Tj	110	°C		
Storage temperature range			T _{stg}	-40~125	°C	
Operating temperature range			T _{opr}	-20~80	°C	
Lead soldering temperature (10s)			T _{sol}	260	°C	
Isolation voltage (AC, 1min., R.H. ≤ 60%) (Note)			BVS	2500	Vrms	

(Note) Device considered a two terminal: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	_	_	120	V _{ac}
Forward current	l _F	15	20	25	mA
Peak current from snubber circuit	I _{SP}	_	_	1	Α
Operating temperature	T _{opr}	-20	_	80	°C

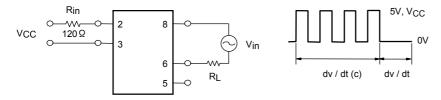
Individual Electrical Characteristics (Ta = 25°C)

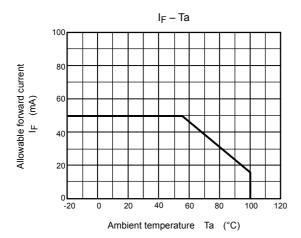
	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1MHz	_	30	_	pF
Detector	Peak off-state current	I _{DRM}	V _{DRM} = 400V, Ta = 110°C	_	_	100	μA
	Peak on-state voltage	V _{TM}	I _{TM} = 0.75A	_	_	3.0	V
	Holding current	lΗ	RL = 100Ω	_	_	25	mA
	Critical rate of rise of off–state voltage	dv / dt	$V_{in} = 120V_{rms}$ (fig.1)	200	500	_	V / µs
	Critical rate of rise of commutating voltage	dv / dt (c)	$V_{in} = 120V_{rms}, I_T = 0.5A_{rms}$ (fig. 1)	_	5	_	V / µs

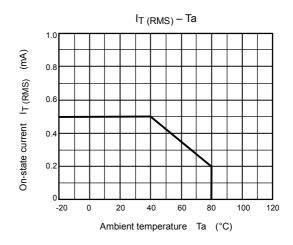
Coupled Electrical Characteristics (Ta = 25°C)

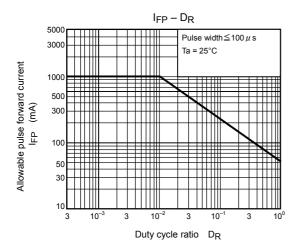
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V _T =6V	_	_	10	mA
Inhibit voltage	V _{IH}	I _F =Rated I _{FT}	_	_	50	V
Leakage in inhibited state	lіН	I _F =Rated I _{FT} V _T = Rated V _{DRM}	_	200	1	μΑ
Capacitance (input to output)	C _S	V _S =0, f=1MHz	_	0.8	١	pF
Isolation resistance	R _S	V _S =500V	5×10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC, 1 minute	2500	_	_	V _{rms}
Isolation voltage		AC, 1 second, in oil	_	5000	_	
		DC, 1 minute, in oil	_	5000	_	V _{dc}

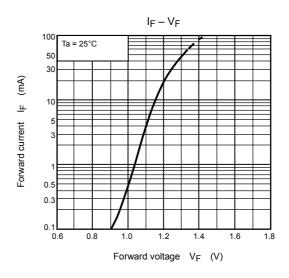
Fig.1: dv / dt test circuit

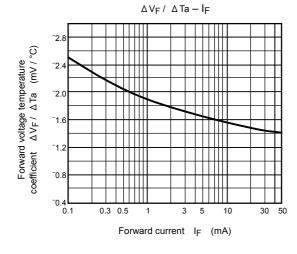


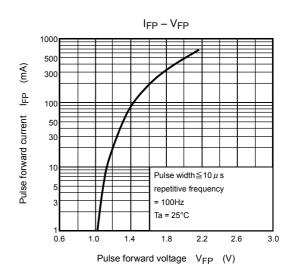


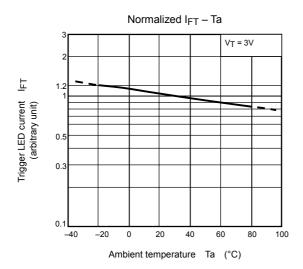


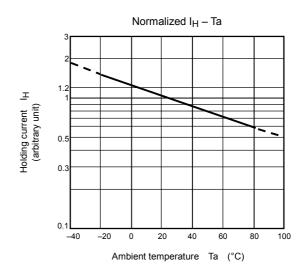


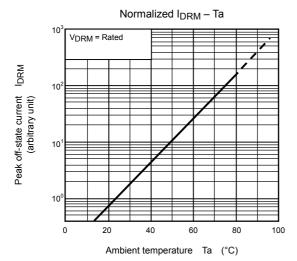


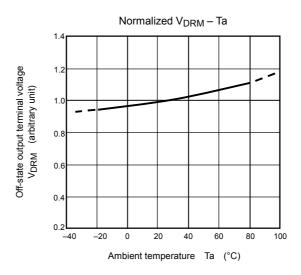


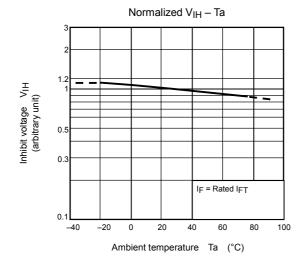


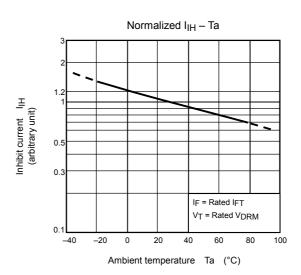












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